

N-channel 40 V, 13.6 mOhm, logic level MOSFET in LFPAK56D using NextPowerS3 technology 26 September 2022 Produc

Product data sheet

## 1. General description

Dual logic level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using NextPowerS3 technology.

## 2. Features and benefits

- Dual MOSFET
- Repetitive avalanche rated
- High reliability LFPAK56D package
- Copper-clip, solder die attach
- Qualified to 175 °C

## 3. Applications

- Brushless DC motor control
- DC-to-DC converters
- High-performance synchronous rectification
- · High performance and high efficiency server power supply

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	40	V
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	-	42	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	46	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics FET1 and FET2	,	-	-			
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 25 °C		7.9	11.4	13.6	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 105 °C		10.9	16	20.4	mΩ
Dynamic ch	naracteristics FET1 and FE	T2					
Q <sub>GD</sub>	gate-drain charge	$I_D$ = 10 A; V <sub>DS</sub> = 32 V; V <sub>GS</sub> = 5 V; T <sub>j</sub> = 25 °C		-	1.8	4.2	nC
Q <sub>G(tot)</sub>	total gate charge	$I_D$ = 10 A; V <sub>DS</sub> = 32 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C		-	13	19.4	nC
Avalanche	Ruggedness FET1 and FE	Γ2					
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D$ = 39.9 A; $V_{sup} \le 40$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; <u>Fig. 4</u>	[2] [3]	-	-	10.6	mJ

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Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Source-drain d	iode FET1 and FET2						
Qr		$\label{eq:IS} \begin{split} I_{S} &= 10 \text{ A}; \ dI_{S}/dt = -100 \text{ A}/\mu\text{s}; \ V_{GS} = 0 \text{ V}; \\ V_{DS} &= 20 \text{ V}; \ T_{j} = 25 \ ^{\circ}\text{C} \end{split}$	[4]	-	16.2	-	nC

[1] 42A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

[4] Includes capacitive recovery

## 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	S1	source1	8 7 6 5					
2	G1	gate1		D1 D1 D2 D2				
3	S2	source2						
4	G2	gate2						
5	D2	drain2						
6	D2	drain2						
7	D1	drain1						
8	D1 drain1	drain1	LFPAK56D; Dual LFPAK (SOT1205)	mbk725				

## 6. Ordering information

#### Table 3. Ordering information

Type number	Package	ackage						
	Name	Description	Version					
PSMN014-40HLD		plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205					

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN014-40HLD	14DS40H

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C	-	40	V
V <sub>GS</sub>	gate-source voltage	DC; T <sub>j</sub> = 25 °C	-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	46	W

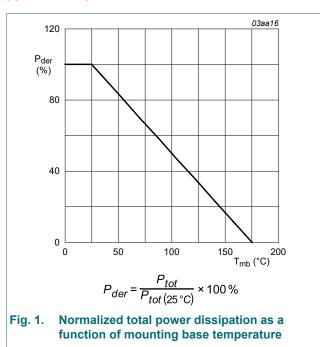
Symbol	Parameter	Conditions		Min	Max	Unit
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	42	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>		-	30	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$ ; Fig. 3		-	169	А
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drain d	iode FET1 and FET2					
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C		-	42	А
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	169	А
Avalanche Rug	gedness FET1 and FET2	·				·
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D$ = 39.9 A; $V_{sup} \le 40$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; <u>Fig. 4</u>	[2] [3]	-	10.6	mJ
I <sub>AS</sub>	non-repetitive avalanche current	$V_{sup}$ = 40 V; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; R <sub>GS</sub> = 50 Ω; Fig. 4	[4]	-	39.9	A

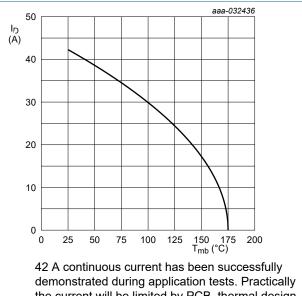
[1] 42A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

[4] Protected by 100% test

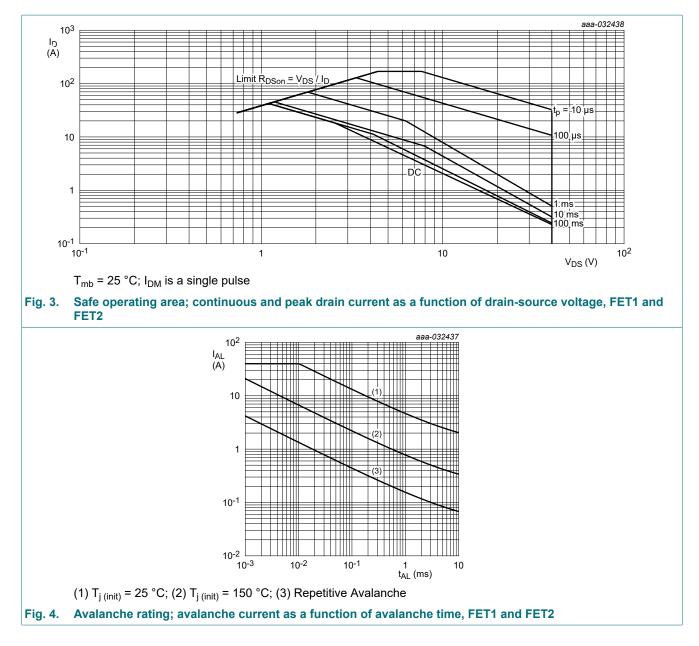




the current will be limited by PCB, thermal design and operating temperature.  $V_{GS} \ge 10 \text{ V}$ 

Fig. 2. Continuous drain current as a function of mounting base temperature, FET1 and FET2

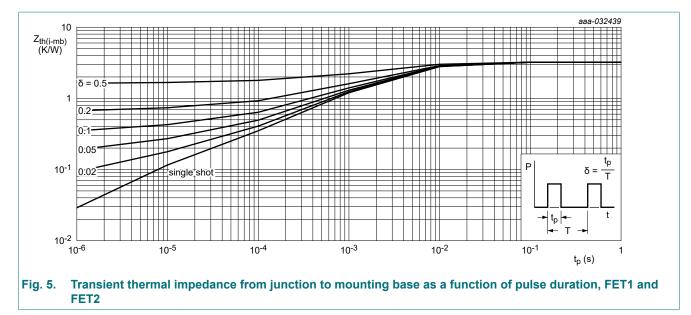
PSMN014-40HLD



## 9. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	3	3.23	K/W

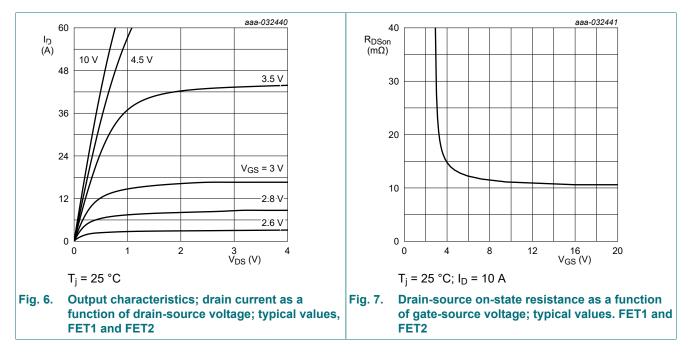


## **10. Characteristics**

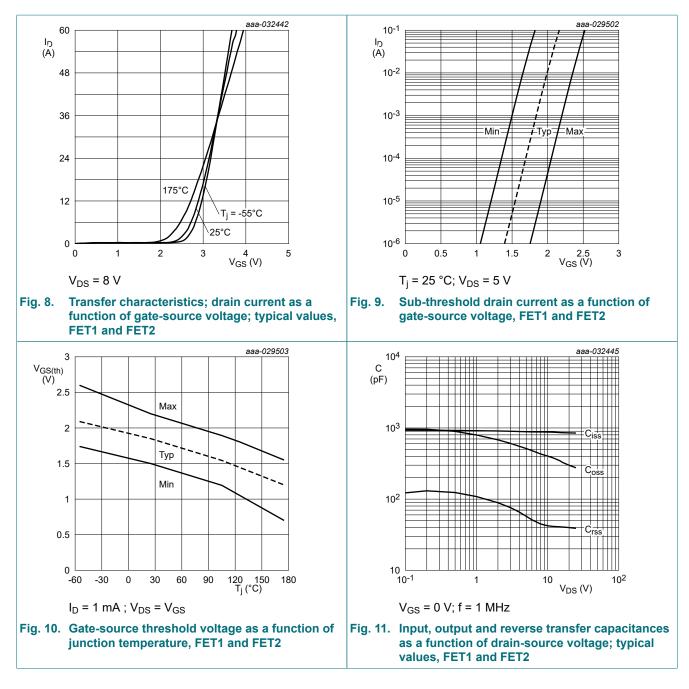
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics FET1 and FET2					
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	40	43	-	V
	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -40 °C	-	40.5	-	V
		I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	36	40	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 25 °C; <u>Fig. 9;</u> <u>Fig. 10</u>	1.5	1.85	2.2	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; Fig. 10	0.7	-	-	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = -55 °C; <u>Fig. 10</u>	-	-	2.6	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.01	5	μA
		V <sub>DS</sub> = 16 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	0.14	10	μA
		V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	26	500	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
		V <sub>GS</sub> = 16 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 25 °C	7.9	11.4	13.6	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 105 °C	10.9	16	20.4	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 125 °C	12	17.4	21.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 175 °C	14.5	20.9	26.4	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 25 °C	9.8	14.1	16.9	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 105 °C	13.5	20	25.4	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 125 °C	14.8	21.6	27.2	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 10 A; T <sub>j</sub> = 175 °C	18	26.6	32.8	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	0.7	1.8	4.2	Ω

Symbol	Parameter	Conditions	N	lin	Тур	Max	Unit
Dynamic ch	naracteristics FET1 and FE	T2	11				
Q <sub>G(tot)</sub>	total gate charge	$I_D$ = 10 A; V <sub>DS</sub> = 32 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C	-		13	19.4	nC
		I <sub>D</sub> = 10 A; V <sub>DS</sub> = 32 V; V <sub>GS</sub> = 5 V;	-		6.8	10.2	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-		2.3	3.8	nC
Q <sub>GD</sub>	gate-drain charge		-		1.8	4.2	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-		848	1160	pF
C <sub>oss</sub>	output capacitance		-		280	420	pF
C <sub>rss</sub>	reverse transfer capacitance		-		39	84	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 32 V; R <sub>L</sub> = 3.2 Ω; V <sub>GS</sub> = 5 V;	-		6.5	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 5 Ω; T <sub>j</sub> = 25 °C	-		9.7	-	ns
t <sub>d(off)</sub>	turn-off delay time		-		10.1	-	ns
t <sub>f</sub>	fall time	_	-		7.8	-	ns
Source-dra	in diode FET1 and FET2						
V <sub>SD</sub>	source-drain voltage	$I_{S}$ = 10 A; $V_{GS}$ = 0 V; $T_{j}$ = 25 °C; <u>Fig. 12</u>	-		0.81	1	V
t <sub>rr</sub>	reverse recovery time	$I_{S} = 10 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-		21.5	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 20 V; T <sub>j</sub> = 25 °C	[1] -		16.2	-	nC

[1] Includes capacitive recovery

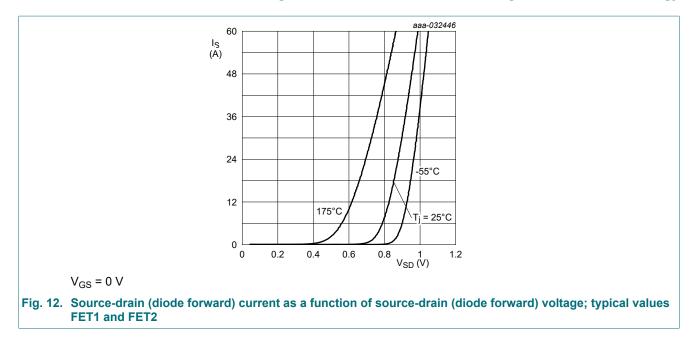


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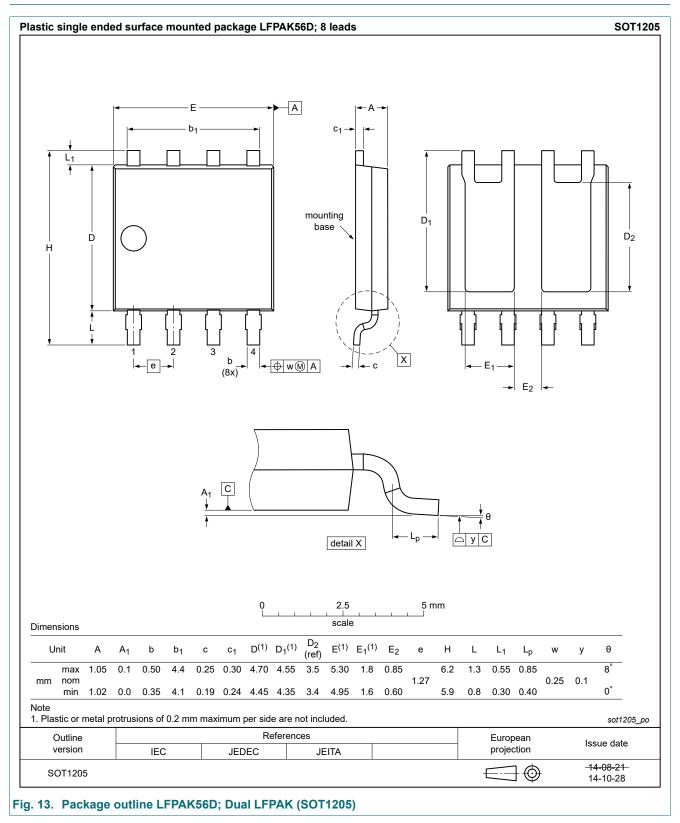
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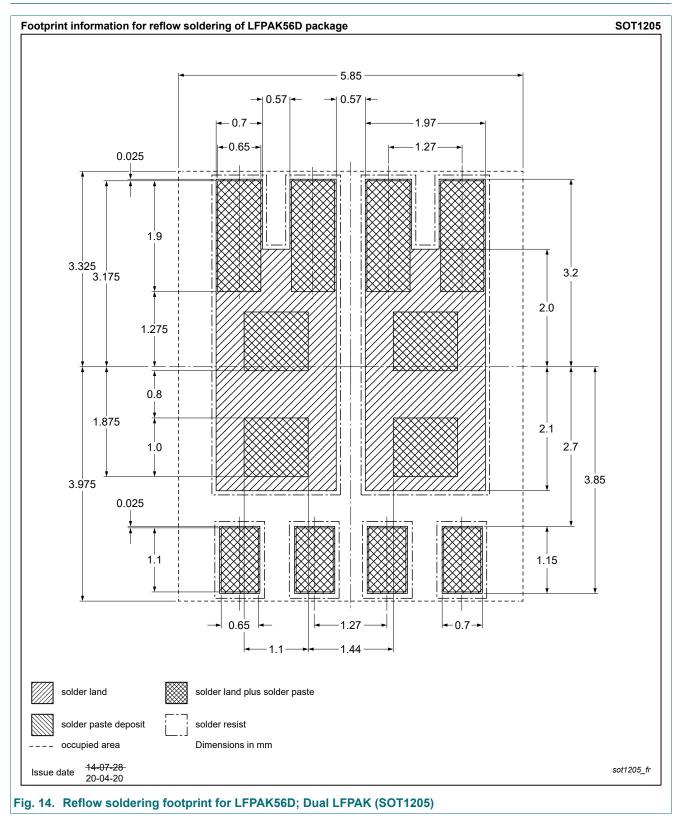


PSMN014-40HLD

## 11. Package outline



## 12. Soldering



## 13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## Contents

1.	General description	.1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	.1
5.	Pinning information	.2
6.	Ordering information	.2
7.	Marking	.2
8.	Limiting values	. 2
9.	Thermal characteristics	. 4
10	Characteristics	. 5
11.	Package outline	. 9
12	. Soldering	10
13	. Legal information	11

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